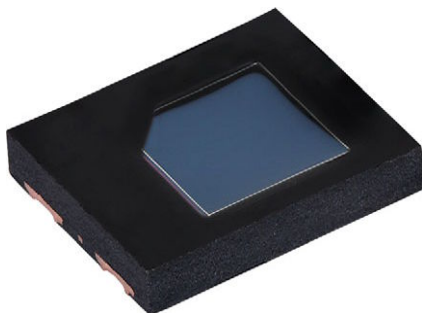


## Silicon PIN Photodiode



### DESCRIPTION

VEMD5080X01 is a high speed and high sensitive PIN photodiode with enhanced sensitivity for visible light. It is a low profile surface-mount device (SMD) including the chip with a 7.5 mm<sup>2</sup> sensitive area detecting visible and near infrared radiation.

### FEATURES

- Package type: surface-mount
- Package form: top view
- Dimensions (L x W x H in mm): 5 x 4 x 0.9
- Radiant sensitive area (in mm<sup>2</sup>): 7.5
- AEC-Q101 qualified
- Enhanced sensitivity for visible light
- Suitable for visible and near infrared radiation
- Fast response times
- Angle of half sensitivity:  $\phi = \pm 65^\circ$
- Floor life: 72 h, MSL 4, according to J-STD-020
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



### APPLICATIONS

- High speed photo detector

### PRODUCT SUMMARY

| COMPONENT   | $I_{ra}$ (μA) | $\phi$ (°) | $\lambda_{0.1}$ (nm) |
|-------------|---------------|------------|----------------------|
| VEMD5080X01 | 45            | $\pm 65$   | 350 to 1100          |

#### Note

- Test conditions see table “Basic Characteristics”

### ORDERING INFORMATION

| ORDERING CODE    | PACKAGING     | REMARKS                      | PACKAGE FORM |
|------------------|---------------|------------------------------|--------------|
| VEMD5080X01      | Tape and reel | MOQ: 1000 pcs, 1000 pcs/reel | Top view     |
| VEMD5080X01-GS15 | Tape and reel | MOQ: 5000 pcs, 5000 pcs/reel | Top view     |

#### Note

- MOQ: minimum order quantity

### ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25^\circ\text{C}$ , unless otherwise specified)

| PARAMETER                              | TEST CONDITION                            | SYMBOL      | VALUE       | UNIT             |
|----------------------------------------|-------------------------------------------|-------------|-------------|------------------|
| Reverse voltage                        |                                           | $V_R$       | 20          | V                |
| Power dissipation                      | $T_{amb} \leq 25^\circ\text{C}$           | $P_V$       | 215         | mW               |
| Junction temperature                   |                                           | $T_j$       | 110         | $^\circ\text{C}$ |
| Operating temperature range            |                                           | $T_{amb}$   | -40 to +110 | $^\circ\text{C}$ |
| Storage temperature range              |                                           | $T_{stg}$   | -40 to +110 | $^\circ\text{C}$ |
| Soldering temperature                  | According to reflow solder profile Fig. 8 | $T_{sd}$    | 260         | $^\circ\text{C}$ |
| Thermal resistance junction to ambient |                                           | $R_{thJA}$  | 350         | K/W              |
| ESD safety HBM                         | $\pm 2000$ V, 1.5 kΩ, 100 pF, 3 pulses    | $ESD_{HBM}$ | $\geq 2$    | kV               |

| <b>BASIC CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                                                             |                 |      |             |      |               |
|-----------------------------------------------------------------------------------------------------|-----------------------------------------------------------------------------|-----------------|------|-------------|------|---------------|
| PARAMETER                                                                                           | TEST CONDITION                                                              | SYMBOL          | MIN. | TYP.        | MAX. | UNIT          |
| Forward voltage                                                                                     | $I_F = 50\text{ mA}$                                                        | $V_F$           | -    | 0.9         | 1.3  | V             |
| Breakdown voltage                                                                                   | $I_R = 100\text{ }\mu\text{A}$ , $E = 0$                                    | $V_{(BR)}$      | 20   | -           | -    | V             |
| Reverse dark current                                                                                | $V_R = 10\text{ V}$ , $E = 0$                                               | $I_{ro}$        | -    | 0.2         | 10   | nA            |
| Diode capacitance                                                                                   | $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$                           | $C_D$           | -    | 80          | -    | pF            |
|                                                                                                     | $V_R = 3\text{ V}$ , $f = 1\text{ MHz}$ , $E = 0$                           | $C_D$           | -    | 30          | 40   | pF            |
| Open circuit voltage                                                                                | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$                        | $V_o$           | -    | 320         | -    | mV            |
| Temperature coefficient of $V_o$                                                                    | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$                        | $TK_{V_o}$      | -    | -3.0        | -    | mV/K          |
| Short circuit current                                                                               | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$                        | $I_k$           | -    | 45          | -    | $\mu\text{A}$ |
| Temperature coefficient of $I_k$                                                                    | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$                        | $TK_{I_k}$      | -    | 0.1         | -    | %/K           |
| Reverse light current                                                                               | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 950\text{ nm}$ , $V_R = 5\text{ V}$   | $I_{ra,IR}$     | 33   | 45          | 53   | $\mu\text{A}$ |
|                                                                                                     | $E_e = 0.2\text{ mW/cm}^2$ , $\lambda = 525\text{ nm}$ , $V_R = 5\text{ V}$ | $I_{ra,G}$      | 3.1  | 5.0         | 6.6  | $\mu\text{A}$ |
|                                                                                                     | $E_e = 1\text{ mW/cm}^2$ , $\lambda = 460\text{ nm}$ , $V_R = 5\text{ V}$   | $I_{ra,B}$      | 13.5 | 18          | 25   | $\mu\text{A}$ |
| Angle of half sensitivity                                                                           |                                                                             | $\phi$          | -    | $\pm 65$    | -    | $^{\circ}$    |
| Wavelength of peak sensitivity                                                                      |                                                                             | $\lambda_p$     | -    | 950         | -    | nm            |
| Range of spectral bandwidth                                                                         |                                                                             | $\lambda_{0.1}$ | -    | 350 to 1100 | -    | nm            |
| Rise time                                                                                           | $V_R = 10\text{ V}$ , $R_L = 1\text{ k}\Omega$ , $\lambda = 830\text{ nm}$  | $t_r$           | -    | 70          | -    | ns            |
| Fall time                                                                                           | $V_R = 10\text{ V}$ , $R_L = 1\text{ k}\Omega$ , $\lambda = 830\text{ nm}$  | $t_f$           | -    | 70          | -    | ns            |

**BASIC CHARACTERISTICS** ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)

Basic characteristics graphs to be extended to 110  $^{\circ}\text{C}$  ambient temperatures where applicable.

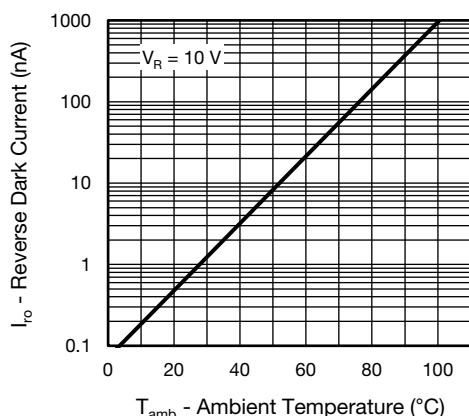


Fig. 1 - Reverse Dark Current vs. Ambient Temperature

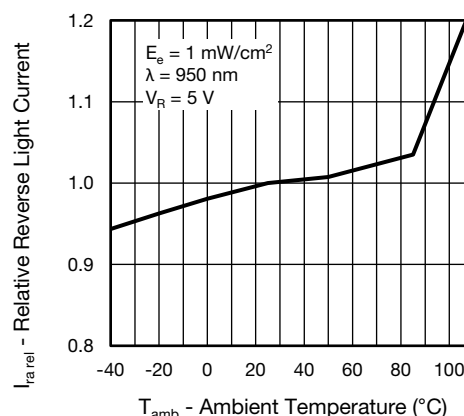


Fig. 2 - Relative Reverse Light Current vs. Ambient Temperature

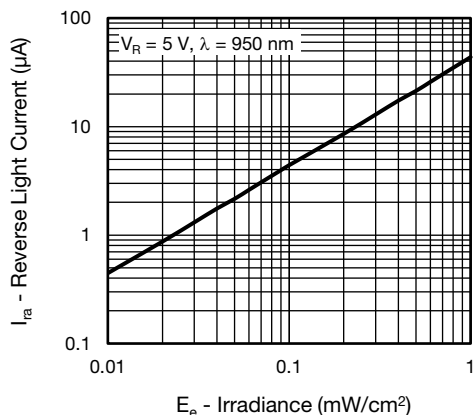


Fig. 3 - Reverse Light Current vs. Irradiance

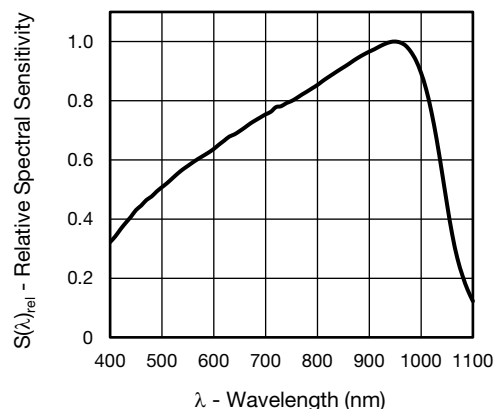


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

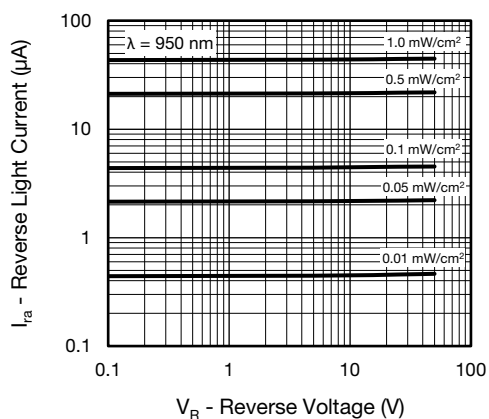


Fig. 4 - Reverse Light Current vs. Reverse Voltage

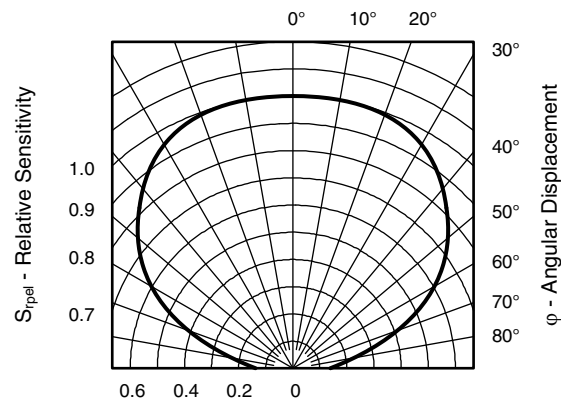


Fig. 7 - Relative Sensitivity vs. Angular Displacement

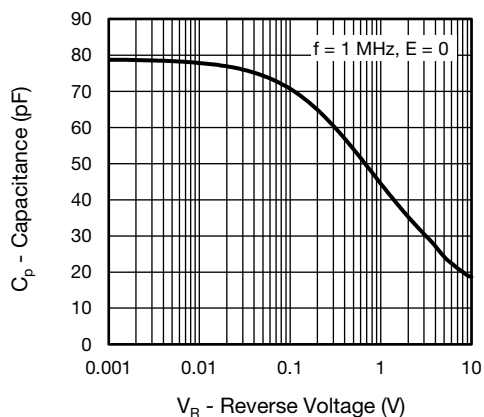
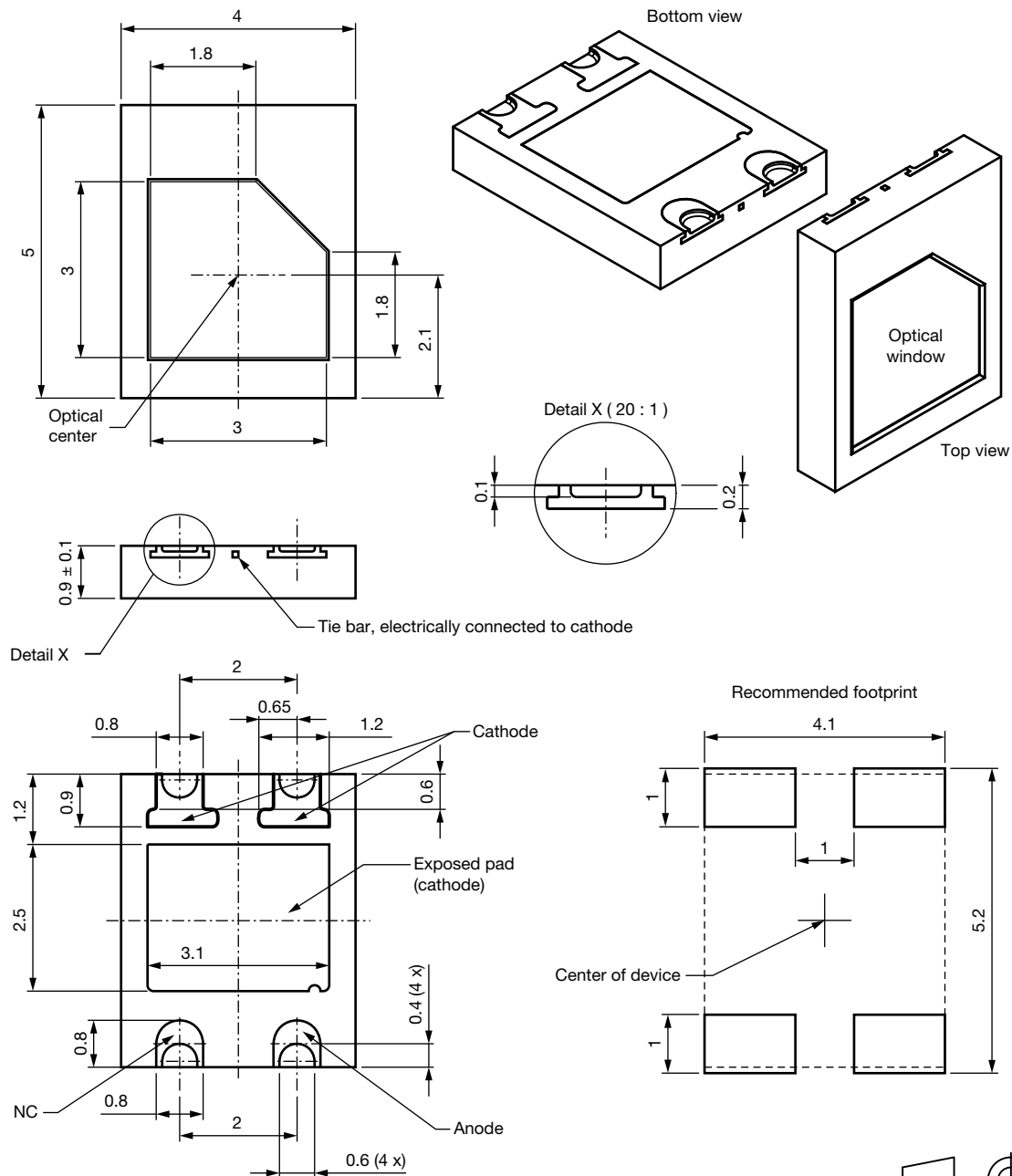
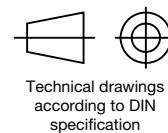


Fig. 5 - Diode Capacitance vs. Reverse Voltage

**PACKAGE DIMENSIONS** in millimeters


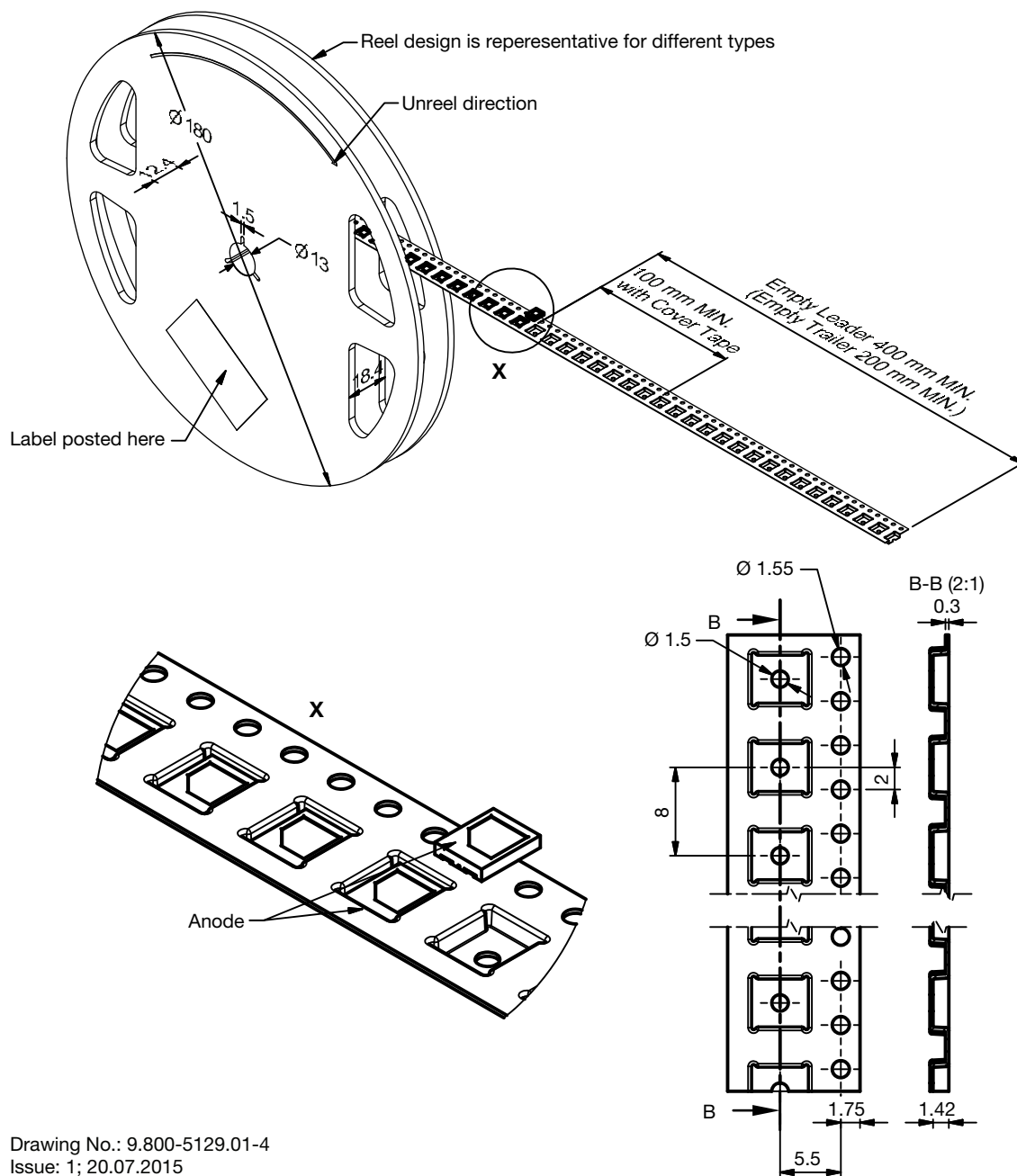
Drawing- No.: 6.550-5329.01-4  
Issue: 5; 23.09.2020

Not indicated tolerances  $\pm 0.1$





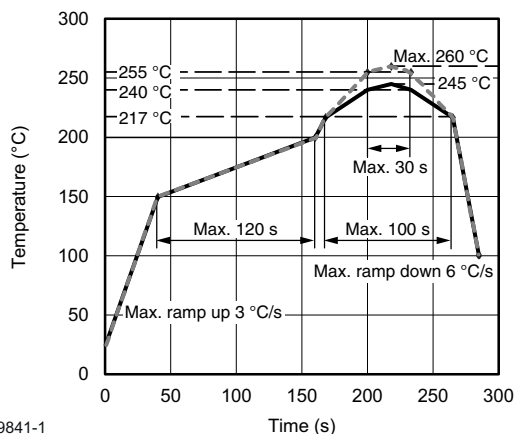
TAPE AND REEL DIMENSIONS in millimeters



Drawing No.: 9.800-5129.01-4  
Issue: 1; 20.07.2015



## SOLDER PROFILE



19841-1

Fig. 8 - Lead (Pb)-free Reflow Solder Profile  
According to J-STD-020D

## DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

## FLOOR LIFE

Time between soldering and removing from MBB must not exceed the time indicated in J-STD-020:

Moisture sensitivity: level 4

Floor life: 72 h

Conditions:  $T_{amb} < 30\text{ °C}$ ,  $RH < 60\%$

## DRYING

In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or recommended conditions:

192 h at  $40\text{ °C}$  (+ 5 °C),  $RH < 5\%$

or

96 h at  $60\text{ °C}$  (+ 5 °C),  $RH < 5\%$



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